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NMAM INSTITUTE OF TECHNOLOGY, NITTE
Off-Campus Centre of Nitte (Deemed to be University)
I Sem B.Tech. (CBCS) Mid Semester Examinations - I, September 2022

PH1001-1 – ENGINEERING PHYSICS

Max. Marks: 20

Duration: 1 Hour

Note: Answer any One full question from each Unit.

List of constants: Velocity of light, $c=3 \times 10^8 \text{ ms}^{-1}$, Planck's constant, $h=6.63 \times 10^{-34} \text{ Js}$,
 Electron mass, $m=9.11 \times 10^{-31} \text{ kg}$, Electron charge, $e=1.6 \times 10^{-19} \text{ C}$,
 Boltzmann constant, $k=1.38 \times 10^{-23} \text{ J/K}$, Neutron mass $=1.68 \times 10^{-27} \text{ kg}$.
 Avogadro number, $N_A = 6.023 \times 10^{26} / \text{kg mole}$.

		Marks	BT*	CO*	PO*
Unit – I					
1.	a) Explain the terms (i) Matter waves (ii) Probability density	3	L*1	1	1,2
	b) Obtain the expression for one-dimensional time independent Schrodinger's wave equation.	4	L2	1	1,2
	c) Calculate the de-Broglie wavelength of an electron moving with an energy of 1.5 keV.	3	L3	1	1,2
2.	a) What are the characteristics of wave function?	3	L1	1	1,2
	b) Solve the Schrodinger's wave equation for a particle in one dimensional potential well of infinite height.	4	L3	1	1,2
	c) An electron is bound in a one-dimensional potential of width 1.5 Å, but of infinite wall height. Find its energy values in the ground state, and in the first excited states.	3	L3	1	1,2
Unit – II					
3.	a) With neat diagram, explain any three crystal systems.	3	L1	2	1,2
	b) What is inter-planar spacing? Obtain an expression for inter-planar spacing in terms of lattice parameter and Miller indices for a cubic crystal.	4	L2	2	1,2
	c) The lattice constant for a unit cell of aluminum is 4.031 Å. Calculate the interplanar spacing of (2 1 1) planes.	3	L3	2	1,2
4.	a) Explain the origin of characteristic X rays.	3	L1	2	1,2
	b) What is atomic packing factor? Determine the atomic packing factor for a face centered cubic (FCC) lattice by calculating number of atoms/unit cell and the relation between atomic radius and lattice constant.	4	L2	2	1,2
	c) Draw a cubic unit cell and plot the following planes: (1 4 1) and (3 2 1)	3	L3	2	1,2

BT* Bloom's Taxonomy, L* Level; CO* Course Outcome; PO* Program Outcome

MAM INSTITUTE OF TECHNOLOGY, NITTE
Off-Campus Centre of Nitte (Deemed to be University)
I Sem B.Tech. (CBCS) Mid Semester Examinations - II, November 2022

Duration: 1 Hour

PH1001-1 – ENGINEERING PHYSICS

Max. Marks: 20

Note: Answer any One full question from each Unit.

List of constants: Velocity of light, $c = 3 \times 10^8 \text{ ms}^{-1}$, Planck's constant, $h = 6.63 \times 10^{-34} \text{ Js}$,
Electron mass, $m = 9.11 \times 10^{-31} \text{ kg}$, Electron charge, $e = 1.6 \times 10^{-19} \text{ C}$,
Boltzmann constant, $k = 1.38 \times 10^{-23} \text{ J/K}$, Mass of neutron $= 1.68 \times 10^{-27} \text{ Kg}$.
Avogadro number, $N_A = 6.023 \times 10^{26} / \text{kg mole}$.

		Marks	BT*	CO*	PO*
Unit – I					
1.	a) Distinguish between intrinsic and extrinsic semiconductor.	3	L*2	3	1,2
	b) Obtain an expression for the conductivity of an extrinsic semiconductor	4	L3	3	1,2
	c) Calculate the resistivity of intrinsic germanium if the intrinsic carrier density is $2.5 \times 10^{19} \text{ m}^{-3}$ assuming electron and hole mobilities of $0.38 \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$ and $0.18 \text{ m}^2 \text{ V}^{-1} \text{ s}^{-1}$ respectively.	3	L3	3	1,2
2.	a) Explain the effect of temperature on the Fermi level in a n-type semiconductor	3	L2	3	1,2
	b) What is Fermi factor? Discuss the variation of Fermi factor for different energy levels with temperature	4	L2	3	1,2
	c) Calculate the probability of an electron occupying an energy level 0.02 eV above the Fermi level at 200 K	3	L3	3	1,2
Unit – II					
3.	a) Distinguish between direct and indirect band-gap semiconductors	3	L2	4	1,2
	b) What is Hall effect? Obtain an expression for the Hall coefficient and Hall voltage of an n-type semiconductor	4	L2	4	1,2
	c) A semiconductor sample of thickness $1.2 \times 10^{-4} \text{ m}$ is placed in a magnetic field of 0.2T acting perpendicular to its thickness. Find the Hall voltage generated when a current of 100 mA passes through it. Assume the carrier concentration to be 10^{23} m^{-3}	3	L3	4	1,2
4.	a) Explain Type-II superconductors with suitable diagrams.	3	L2	4	1,2
	b) What are superconductors? Explain Critical magnetic field and Meissner effect in superconductors.	4	L2	4	1,2
	c) The critical temperature and critical magnetic field for superconducting lead are 7.2 K and 800 gauss respectively. What will be the temperature up to which lead will be in superconducting state in a magnetic field of 400 gauss?	3	L3	4	1,2

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